

TOSHIBA Photocoupler Photo Relay

# TLP597GA

Cordless Telephone

PBX

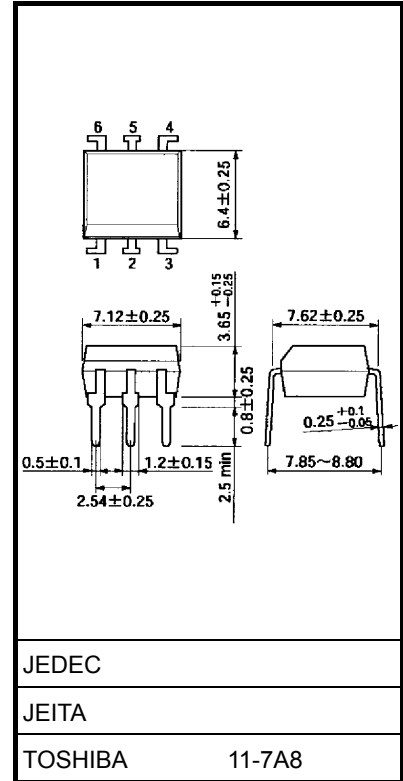
Modem

The TOSHIBA TLP597GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).

The TLP597GA is a bi-directional switch can replace mechanical relays in many applications.

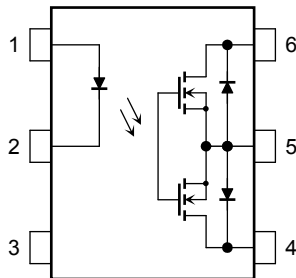
- 6 pin DIP (DIP6)
- 1-form-A
- Peak off-state voltage: 400 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance: 35 Ω (max)
- Isolation voltage: 2500 Vrms (min)
- UL Recognized :UL1577, File No. E67349

Unit: mm



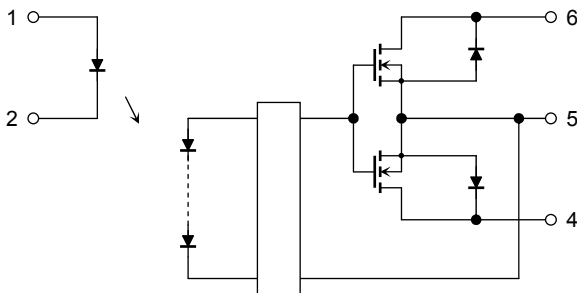
Weight: 0.4 g (typ.)

### Pin Configuration (top view)



- 1 : ANODE
- 2 : CATHODE
- 4 : DRAIN D1
- 5 : SOURCE
- 6 : DRAIN D2

### Schematic



## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
LED	Forward current	$I_F$	50	mA	
	Forward current derating (Ta ≥ 25°C)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C	
	Peak forward current (100 μs pulse, 100 pps)	$I_{FP}$	1	A	
	Reverse voltage	$V_R$	5	V	
	Junction temperature	$T_j$	125	°C	
Detector	Off-state output terminal voltage		$V_{OFF}$	400	V
	On-state current	A connection	$I_{ON}$	120	mA
		B connection		120	
		C connection		240	
	On-state current derating (Ta ≥ 25°C)	A connection	$\Delta I_{ON}/^\circ\text{C}$	-1.2	mA/°C
		B connection		-1.2	
		C connection		-2.4	
Junction temperature		$T_j$	125	°C	
Storage temperature range		$T_{opr}$	-55 to 125	°C	
Operating temperature range		$T_{stg}$	-40 to 85	°C	
Lead soldering temperature (10 s)		$T_{sol}$	260	°C	
Isolation voltage (AC, 1 min, R.H. ≤ 60%) (Note 1)		$BV_S$	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

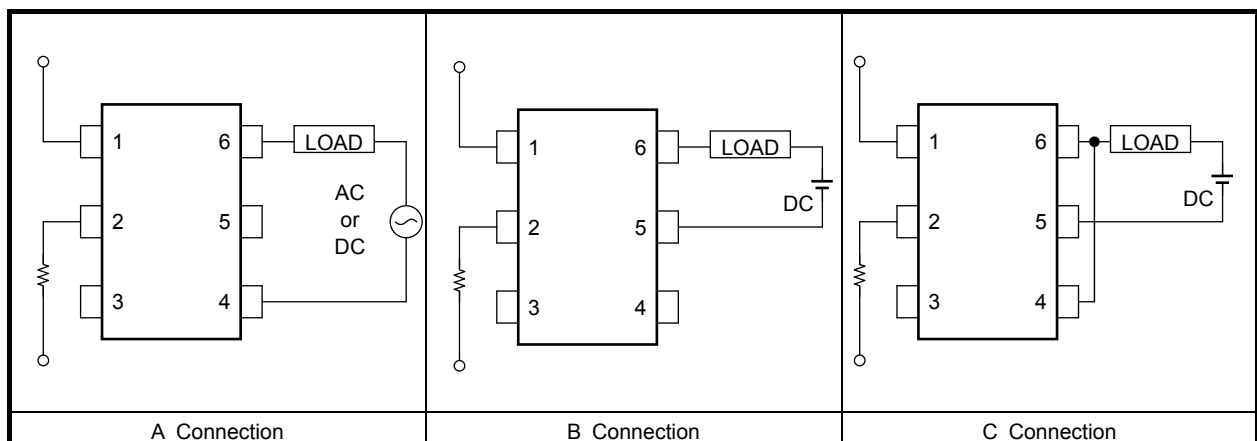
Note 1: Device considered a two-terminal device : Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

## Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	$V_{DD}$	—	—	320	V
Forward current	$I_F$	5	7.5	25	mA
On-state current	$I_{ON}$	—	—	120	mA
Operating temperature	$T_{opr}$	-20	—	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## Circuit Connections



## Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Off-state current	$I_{OFF}$	$V_{OFF} = 400 \text{ V}$	—	—	1	$\mu\text{A}$
	Capacitance	$C_{OFF}$	$V = 0, f = 1 \text{ MHz}$	—	70	—	pF

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current		$I_{FT}$	$I_{ON} = 120 \text{ mA}$	—	1	3	mA
Return LED current		$I_{FC}$	$I_{OFF} = 100 \mu\text{A}$	0.1	—	—	mA
On-state resistance	A connection	$R_{ON}$	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	17	35	$\Omega$
			$I_{ON} = 20 \text{ to } 120 \text{ mA}, I_F = 5 \text{ mA}$	—	20	40	
	B connection		$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	11	20	
	C connection		$I_{ON} = 240 \text{ mA}, I_F = 5 \text{ mA}$	—	6	—	

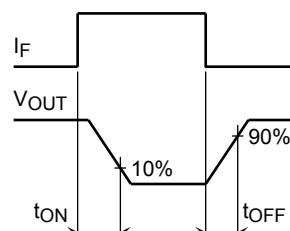
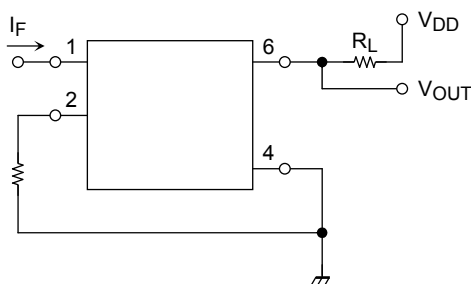
## Isolation Characteristics (Ta = 25°C)

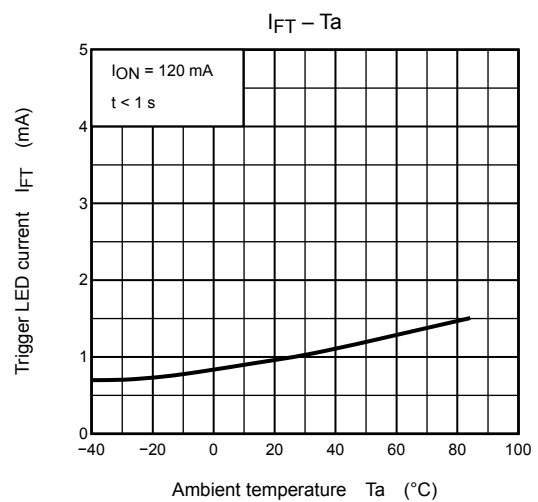
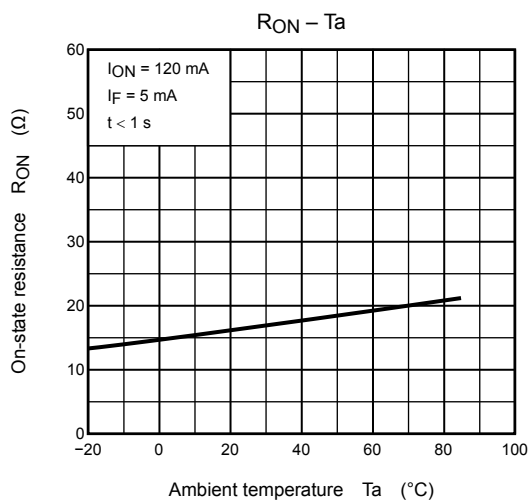
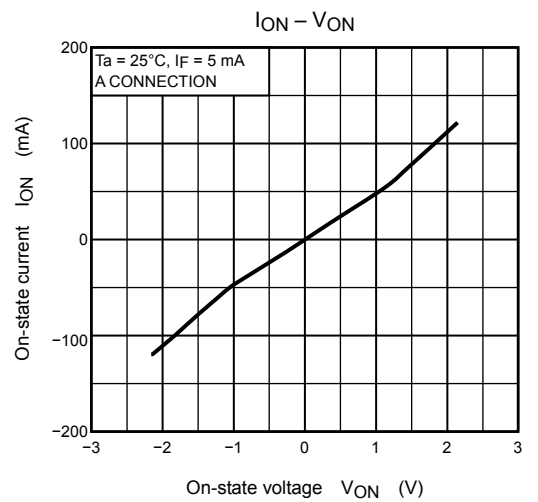
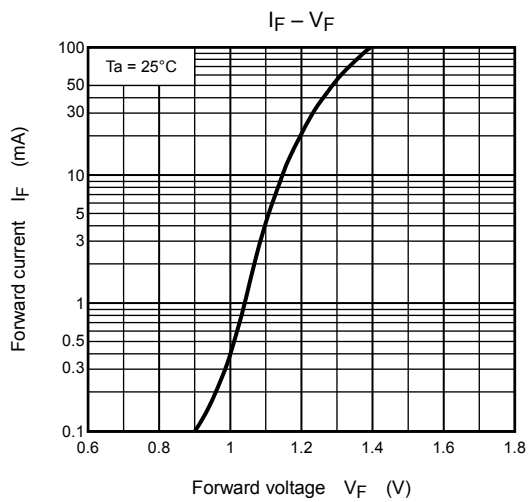
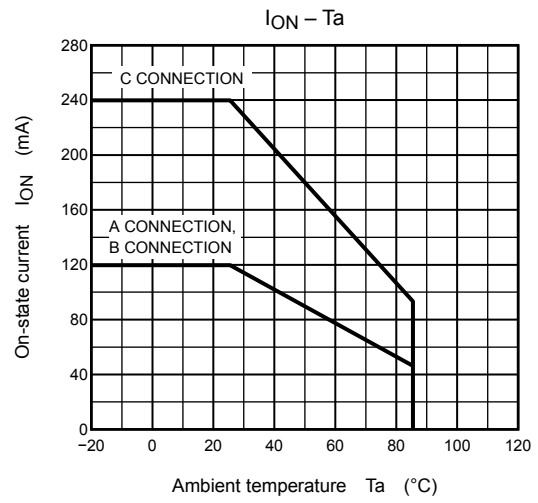
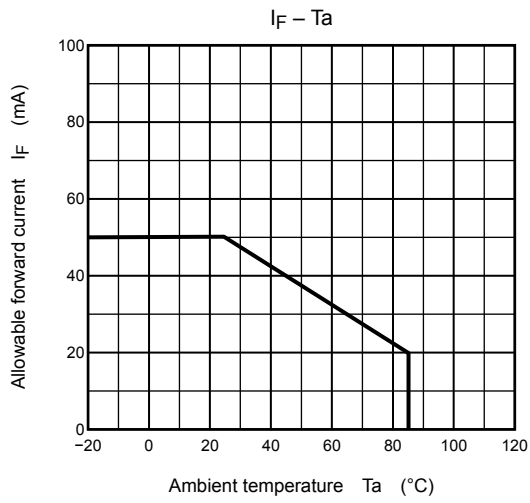
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output		$C_S$	$V_S = 0 \text{ V}, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance		$R_S$	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation voltage		$BV_S$	AC, 1 min	2500	—	—	Vrms
			AC, 1 s (in oil)	—	5000	—	
			DC, 1 min (in oil)	—	5000	—	Vdc

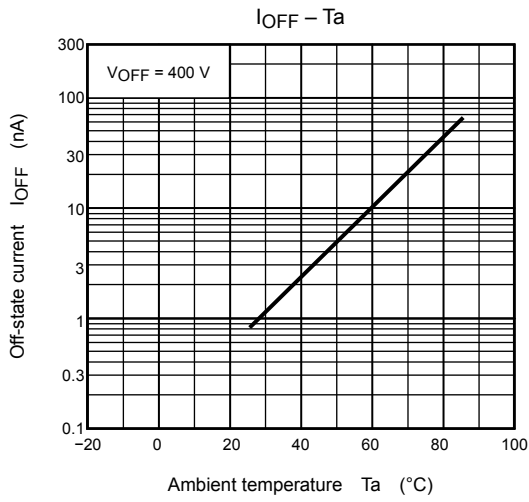
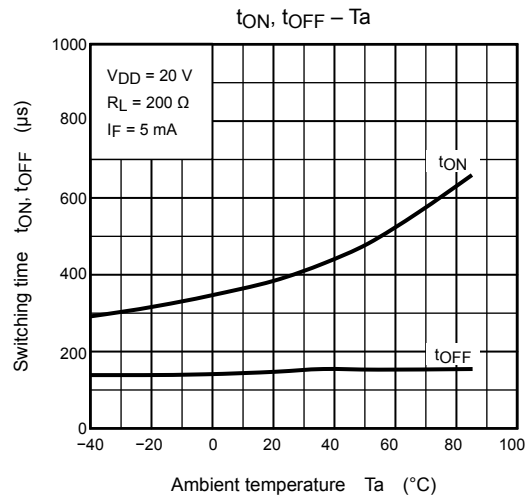
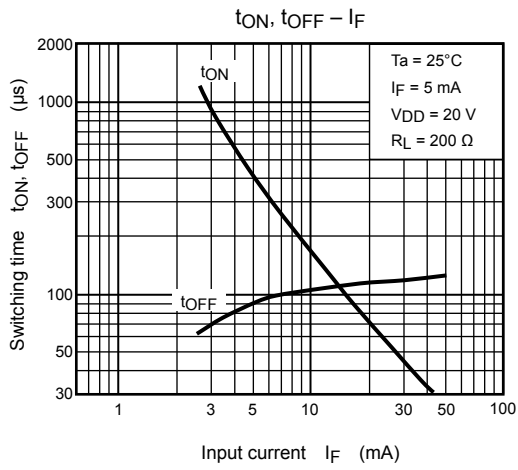
## Switching Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	$t_{ON}$	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	(Note 2)	—	0.3	1	ms
Turn-off time	$t_{OFF}$			—	0.1	1	ms

Note 2: Switching time test circuit







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